

SOT223 N-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET
Features and Benefits

- 6A Pulse Drain Current
- Fast Switching Speed
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Applications

- DC-DC Converters
- Solenoids / Relay Driver for Automotive

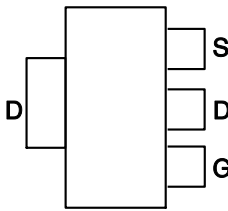
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.112 grams (Approximate)

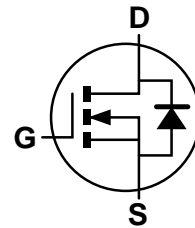
SOT223



Top View



Pin Out - Top



Equivalent Circuit

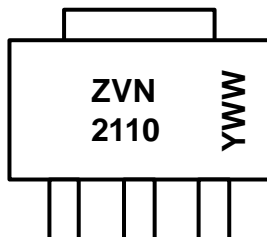
Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZVN2110GTA	ZVN2110	7	8	1,000

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information

SOT223



ZVN2110 = Product Type Marking Code
 YWW = Date Code Marking
 Y or \bar{Y} = Last Digit of Year (ex: 5= 2015)
 WW or $\bar{W}W$ = Week Code (01~53)

ABSOLUTE MAXIMUM RATINGS (@T_A = +25°C, unless otherwise stated.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	100	V
Gate-Source Voltage	V _{GSS}	±20	V
Continuous Drain Current	I _D	500	mA
Pulsed Drain Current	I _{DM}	6	A
Power Dissipation	P _D	2	W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (@T_A = +25°C, unless otherwise stated.)

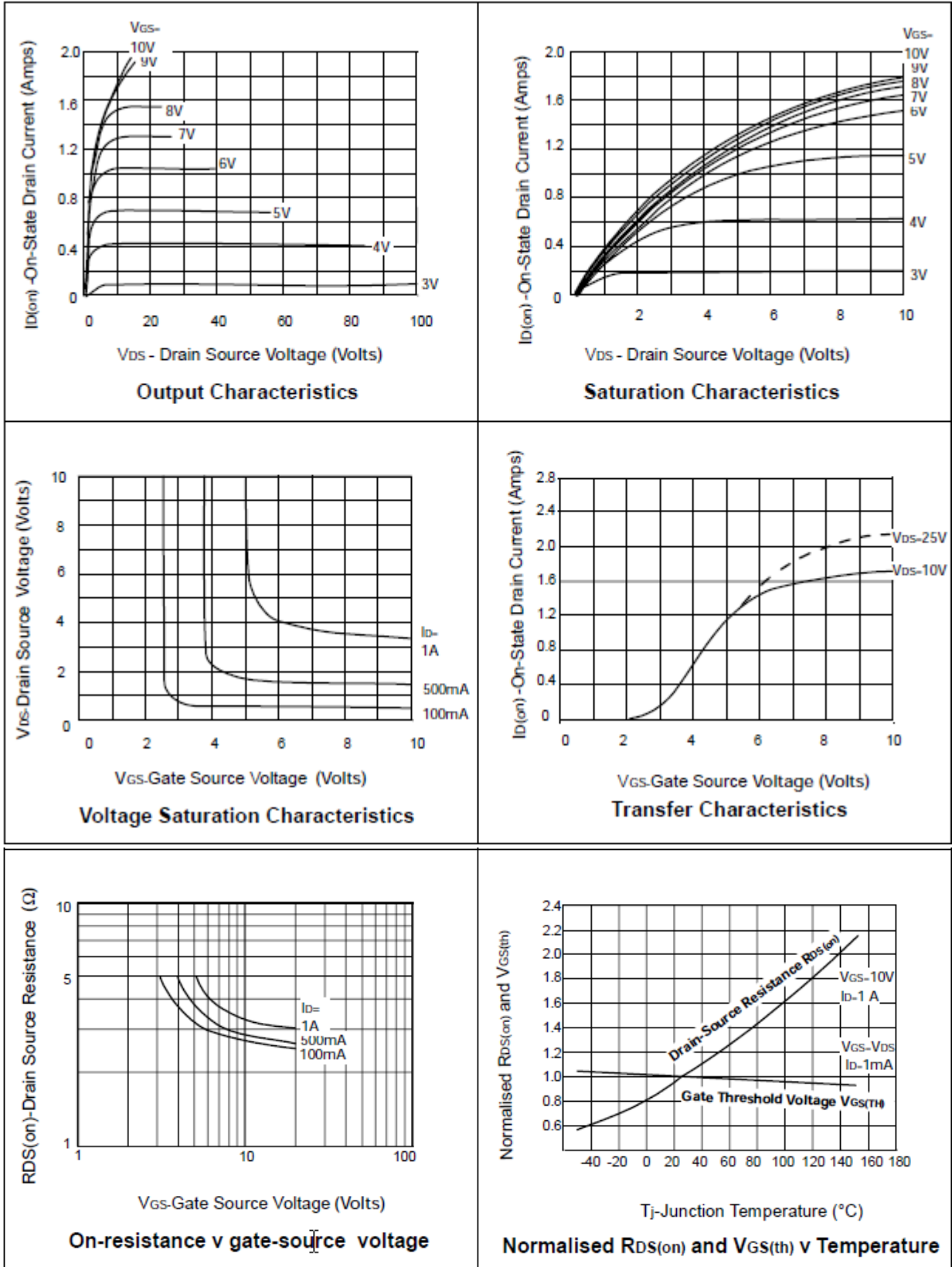
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	100	-	-	V	V _{GS} = 0V, I _D = 1mA
Zero Gate Voltage Drain Current	I _{DSS}	-	-	1 100	μA μA	V _{DS} = 100V, V _{GS} = 0V V _{DS} = 80V, V _{GS} = 0V, T = +125°C(6)
Gate-Body Leakage	I _{GSS}	-	0.1	20	nA	V _{GS} = ±20V, V _{DS} = 0V
On-State Drain Current (Note 5)	I _{D(ON)}	1.5	2	-	A	V _{GS} = 10V, V _{DS} = 25V
ON CHARACTERISTICS						
Gate-Source Threshold Voltage	V _{GS(TH)}	0.8	-	2.4	V	V _{DS} = V _{GS} , I _D = 1mA
Static Drain-Source On-State Resistance (Note 5)	R _{DS(ON)}	-	-	4	Ω	V _{GS} = 10V, I _D = 1A
Forward Transconductance (Notes 5 & 6)	g _{fs}	250	350	-	mS	V _{DS} = 25V, I _D = 1A
DYNAMIC CHARACTERISTICS						
Input Capacitance (Note 6)	C _{iss}	-	59	75	pF	V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz
Common Source Output Capacitance (Note 6)	C _{oss}	-	16	25	pF	
Reverse Transfer Capacitance (Note 6)	C _{rss}	-	4	8	pF	
Turn-On Delay Time (Notes 6 & 7)	t _{D(ON)}	-	4	7	ns	V _{DD} = 25V, I _D = 1A
Rise Time (Notes 6 & 7)	t _R	-	4	8	ns	
Turn-Off Delay Time (Notes 6 & 7)	t _{D(OFF)}	-	8	13	ns	
Fall Time (Notes 6 & 7)	t _F	-	8	13	ns	

DRAIN-SOURCE DIODE CHARACTERISTICS

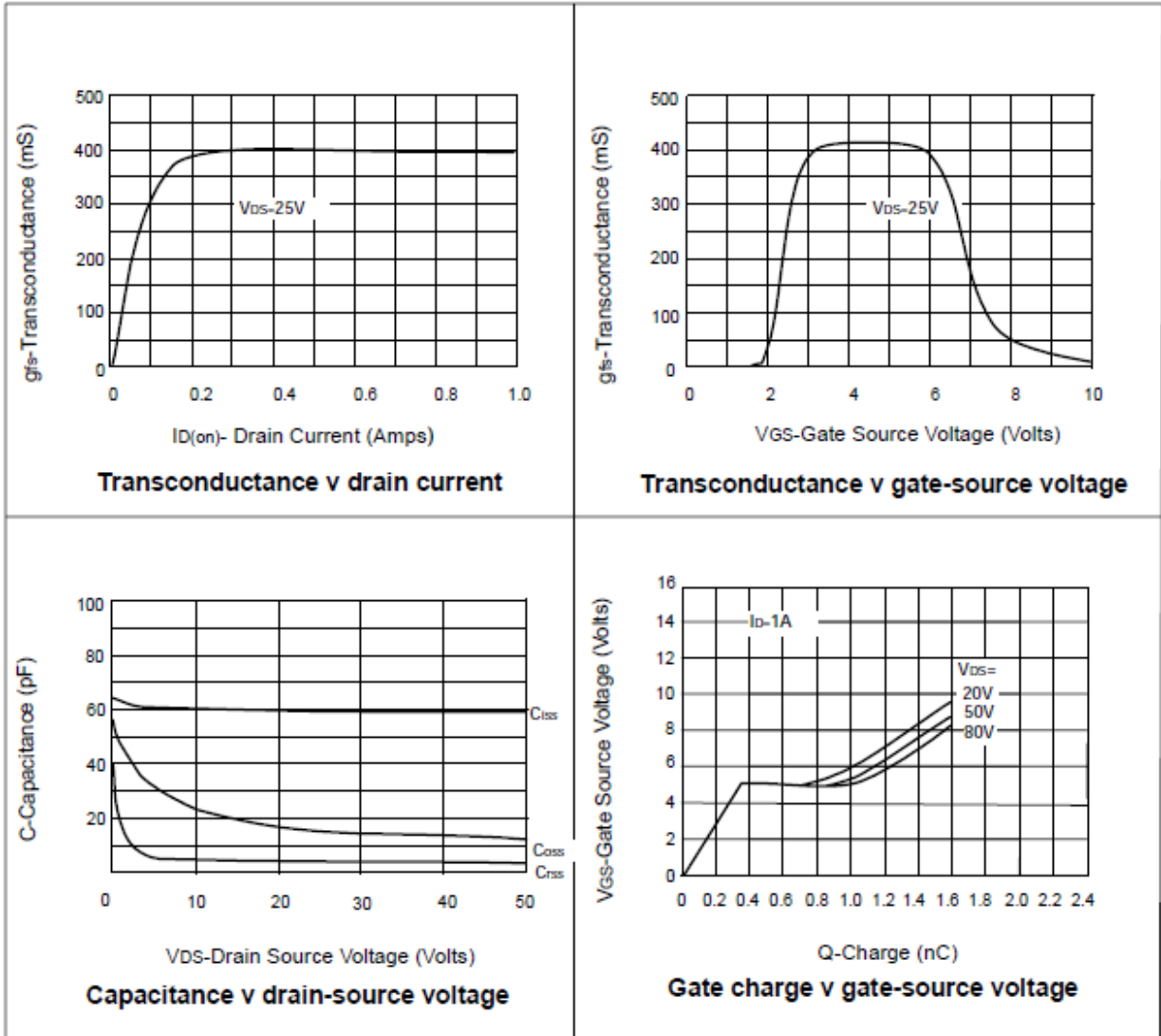
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Diode Forward Voltage (Note 5)	V _{SD}	-	0.82	-	V	I _S =0.32A, V _{GS} =0
Reverse Recovery Time	T _{RR}	-	112	-	ns	I _F =0.32A, V _{GS} =0, I _R =0.1A

- Notes:
5. Measured under pulsed conditions. Width=300μs. Duty cycle ≤2%.
 6. Sample test.
 7. Switching times measured with 50Ω source impedance and <5ns rise time on a pulse generator.

TYPICAL CHARACTERISTICS

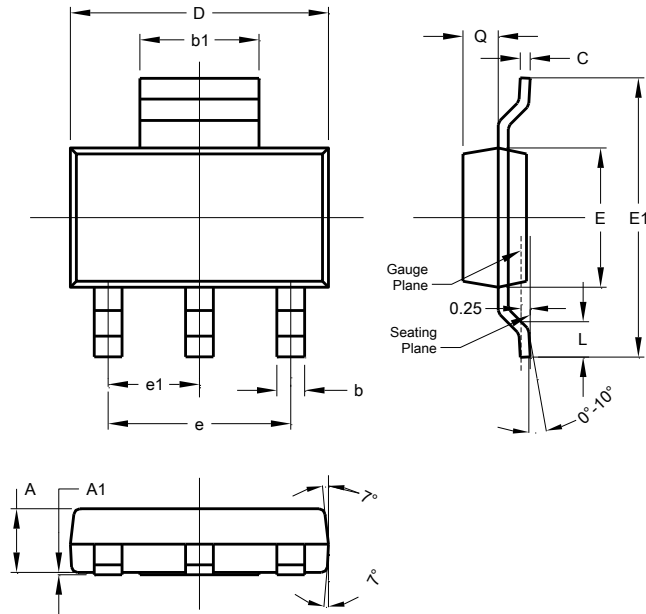


TYPICAL CHARACTERISTICS



Package Outline Dimensions

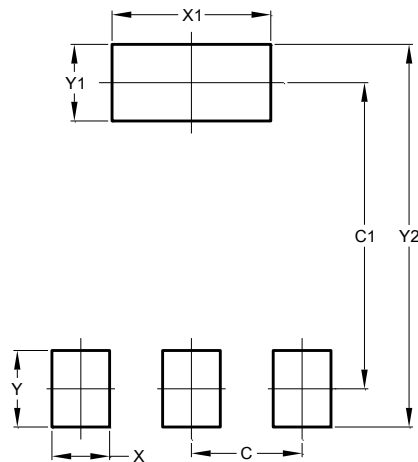
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Diodes Incorporated:](#)

[ZVN2110GTA](#)